

# PHEMT GaAs IC SPDT Switch DC-3 GHz



AS179-92

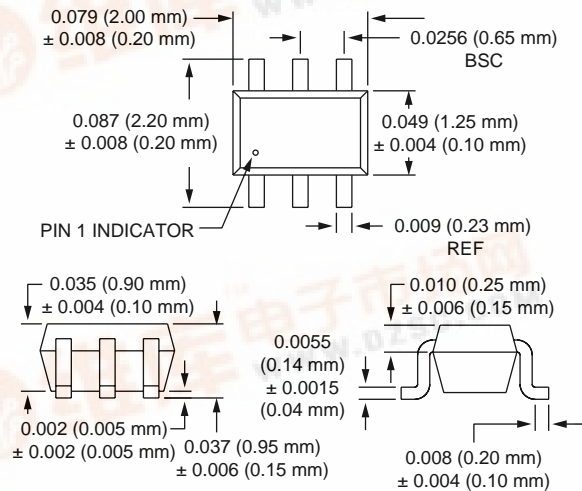
## Features

- P<sub>1</sub> dB +30 dBm Typical @ +3 V
- IP3 43 dBm Typical @ +3 V
- Low Insertion Loss (0.3 dB @ 0.9 GHz)
- Low DC Power Consumption
- Ultra Miniature SC-70 6 Lead Package
- PHEMT Process

## Description

The AS179-92 is an IC FET SPDT switch in a low cost miniature SC-70 6 lead plastic package. The AS179-92 features low insertion loss and positive voltage operation with very low DC power consumption. This general purpose switch can be used in a variety of telecommunications applications.

## SC-70 6 Lead



## Electrical Specifications at 25°C (0, +3 V)

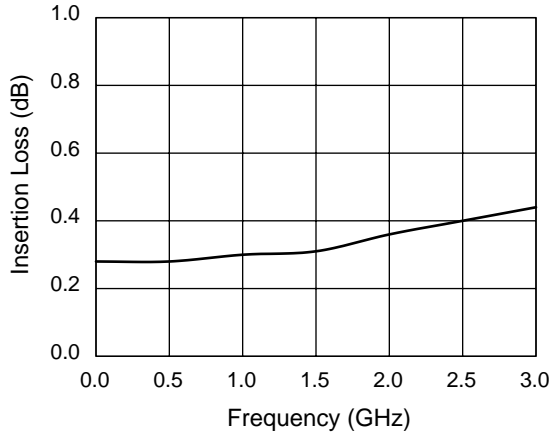
Parameter <sup>1</sup>	Frequency <sup>2</sup>	Min.	Typ.	Max.	Unit
Insertion Loss <sup>3</sup>	DC-1.0 GHz		0.3	0.4	dB
	DC-3.0 GHz		0.4	0.6	dB
Isolation	DC-1.0 GHz	22	25		dB
	DC-2.0 GHz	22	25		dB
	DC-3.0 GHz	20	23		dB
VSWR <sup>4</sup>	DC-1.0 GHz		1.2:1	1.4:1	
	DC-2.0 GHz		1.2:1	1.4:1	
	DC-3.0 GHz		1.3:1	1.4:1	

## Operating Characteristics at 25°C (0, +3 V)

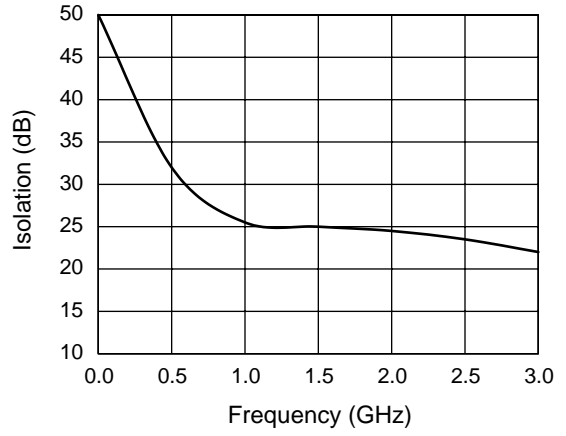
Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics <sup>5</sup>	Rise, Fall (10/90% or 90/10% RF)			10		ns
	On, Off (50% CTL to 90/10% RF)			20		ns
	Video Feedthru			25		mV
Input Power for 1 dB Compression	0/+3 V	0.5-3.0 GHz		+30		dBm
	0/+5 V	0.5-3.0 GHz		+34		dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power +5 dBm					
	0/+3 V	0.5-3.0 GHz		+43		dBm
	0/+5 V	0.5-3.0 GHz		+50		dBm
Control Voltages	V <sub>Low</sub> = 0 to 0.2 V @ 20 μA Max.					
	V <sub>High</sub> = +3 V @ 100 μA Max. to +5 V @ 200 μA Max.					

1. All measurements made in a 50 Ω system, unless otherwise specified.  
 2. DC = 300 kHz.  
 3. Insertion loss changes by 0.003 dB/°C.  
 4. Insertion loss state.  
 5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

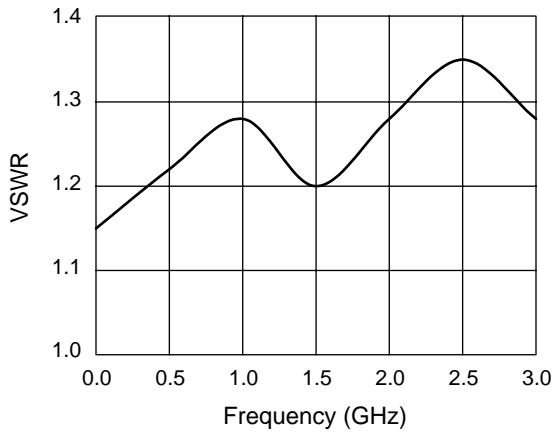
**Typical Performance Data (0, +3 V)**



**Insertion Loss vs. Frequency**



**Isolation vs. Frequency**



**VSWR vs. Frequency**

**Truth Table**

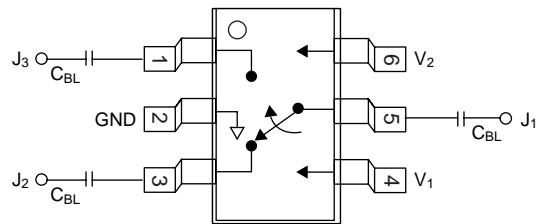
V <sub>1</sub>	V <sub>2</sub>	J <sub>1</sub> -J <sub>2</sub>	J <sub>1</sub> -J <sub>3</sub>
V <sub>High</sub>	0	Isolation	Insertion Loss
0	V <sub>High</sub>	Insertion Loss	Isolation

V<sub>High</sub> = +3 to +5 V.

**Absolute Maximum Ratings**

Characteristic	Value
RF Input Power	6 W > 500 MHz 0/+7 V Control
Control Voltage	-0.2 V, +8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
θ <sub>JC</sub>	25°C/W

**Pin Out**



DC blocking capacitors (C<sub>BL</sub>) must be supplied externally for positive voltage operation.  
C<sub>BL</sub> = 100 pF for operation >500 MHz.